

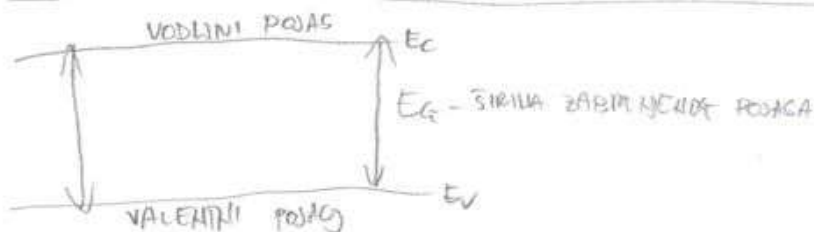
n - konc. slobodnih elektrona
 p - konc. -H⁺ jona

u čistom Si $n=p \rightarrow$ intrinzični Si

koncentracija nosilaca INTRINZIČNA KONC. n_i

H₂ - konc. donora

DOPIRANI Si $n \gg p \rightarrow$ silicij n -tipa ($n \gg p$) > ekstrinzični poluvodič
 $n \ll p \rightarrow$ silicij p -tipa



Intrinzična koncentracija

$$n_i = \underbrace{C \cdot T^{\frac{3}{2}}}_{\text{konstanta poluvod. materijala}} \exp \left[- \frac{E_G(T)}{2 \underbrace{E_T}_{\text{energ. ekvivalent temp.}}} \right]$$

BOGTZMANNOVA KONST

$$E_T = \frac{T}{11600} \text{ eV}$$

$$n_i = C_i \cdot T^{\frac{3}{2}} \exp \left(- \frac{E_{G0}}{2 E_T} \right)$$

ODREĐIVANJE KONC. NOSILACA

KADA SU $F_V = 0 \Rightarrow$ primenjuje se zakon termodinamičke ravnoteže.

$$n_0 \cdot p_0 = n_i^2$$

✓ savršena konc. nosilaca

zakon električne neutralnosti

$$g(p_0 + H_D^+) = g(n_0 + H_A^-)$$

poluvodič n -tipa:

$$N_D > N_A$$

$$n_{0n} = \frac{N_D - N_A + \sqrt{(N_D - N_A)^2 + 4n_i^2}}{2}$$

KONC. MAJINSKIH SUPUTNIKA

$$p_{0m} = \frac{n_i^2}{n_{0n}}$$

KONC. VEĆINSKIH ELEKTRONA

Ekstrinzično term. pobuđeno $\Rightarrow n_{0n} \gg n_i \gg p_{0m} \Rightarrow n_{0n} \approx N_D - N_A$

intrinzični materijal:

$n_0 = p_0$ FERMIJEVA ENERGIJA INTRINZIČNOG POLUVODIČA

$$N_c \exp\left(\frac{E_{Fn} - E_c}{E_T}\right) = N_v \exp\left(\frac{E_v - E_{Fn}}{E_T}\right)$$

$$E_{Fn} = \frac{E_v + E_c}{2} \Rightarrow \text{rednišni potencijal jednak}$$

$$\frac{n_0}{N_c} = \exp\left(2 \frac{E_T - E_{Fn}}{E_T}\right)$$

$$n_0 = n_i \exp\left(\frac{E_F - E_{Fn}}{E_T}\right)$$

$$p_0 = p_i \exp\left(\frac{E_{Fn} - E_F}{E_T}\right)$$

$$E_F = E_{Fn}$$

poluvodič n-tipa:

$$n_{0n} = N_c \exp\left(\frac{E_F - E_c}{E_T}\right) = n_i \exp\left(\frac{E_F - E_{Fn}}{E_T}\right)$$

$$E_F = E_c - E_T \ln\left(\frac{N_c}{n_{0n}}\right) = E_{Fn} + E_T \ln\left(\frac{n_{0n}}{n_i}\right) \quad | \quad n_{0n} \approx N_D - N_A$$

poluvodič p-tipa:

$$p_{0p} = N_v \exp\left(\frac{E_v - E_F}{E_T}\right) = p_i \exp\left(\frac{E_{Fn} - E_F}{E_T}\right)$$

$$E_F = E_v + E_T \ln\left(\frac{N_v}{p_{0p}}\right) = E_{Fn} - E_T \ln\left(\frac{p_{0p}}{p_i}\right) \quad | \quad p_{0p} \approx N_A - N_D$$

DRIFTNA BRZINA ELEKTROMA

$$\vec{v}_{dm} = \mu_n \vec{F}$$

↓
PROVEDLJIVOST
ELEKTROMA

DRIFTNA BRZINA ŠUPČIHA

$$\vec{v}_{dp} = \mu_p \vec{F}$$

↓
PROVEDLJIVOST
ŠUPČIHA

DRIFTNA STRUJA I SPECIFIČNA VODLJIVOST

$$\vec{J}_F = \sigma \cdot \vec{F}$$

↓
SPEC.
VODLJIVOST

- GUSTOĆA DRIFTNE STRUJE

$$\vec{J}_{Fn} = -g n \vec{v}_{dm}$$

↓
koncentracija
elektrona

- DRIFTNA STRUJA ELEKTROMA

$$\vec{J}_{Fn} = g_n \mu_n \vec{F}$$

$$\vec{J}_{Fp} = g_p \mu_p \vec{F} \quad \rightarrow \text{driftna struja šupčih}$$

$$\vec{J}_F = \vec{J}_{Fn} + \vec{J}_{Fp} = g(\mu_n + \mu_p) \vec{F} \quad \rightarrow \text{ukupna driftna struja poluvodiča}$$

$\sigma = q(n\mu_n + p\mu_p)$ - specifinė vadymoji polivodicia

$$\sigma_i = q n_i (\mu_n + \mu_p), \quad n = p = n_i$$

specifinė vadymoji ir ekstensinė polivodicia:

$$\sigma_n = q (H_D - H_A) \mu_n \quad - \text{ n-tipo}$$

$$\sigma_p = q (H_A - H_D) \mu_p \quad - \text{ p-tipo}$$

DIFUZIJUSKA STEUJA

$$J_{Dn} = q D_n \frac{dn(x)}{dx} \quad - \text{ gytocia difuzijuska stuyje elektronu}$$

DIFUZIJUSKA
KONSTANTA
ELEKTRONU

$$\Rightarrow D_n = U_T \cdot \mu_n, \quad U_T = \frac{kT}{q} = \frac{T}{11600}, V$$

$$J_{Dp} = -q D_p \frac{dp(x)}{dx} \quad - \text{ gytocia difuzijuska stuyje supljia}$$

DIFUZIJUSKA
KONSTANTA
SUPLIJA

$$D_p = U_T \cdot \mu_p$$

UKUPNA STEUJA POLIVODICIA

$$\vec{J} = \vec{J}_n + \vec{J}_p$$

$$\vec{J}_n = \vec{J}_{Fn} + \vec{J}_{Dn} = q \cdot n \cdot \mu_n \vec{F} + q \cdot D_n \text{grad} n$$

$$\vec{J}_p = \vec{J}_{Fp} + \vec{J}_{Dp} = q \cdot p \cdot \mu_p \vec{F} - q \cdot D_p \text{grad} p$$